

**APPLICATION DATA SHEET**

**Application Information**

Application Type:: Regular  
Subject Matter:: Utility  
Title:: THERMALLY ANNEALED, LOW DEFECT  
DENSITY SINGLE CRYSTAL SILICON  
Attorney Docket Number:: MEMC 98-1451/2554.1  
Request for Early Publication?:: No  
Request for Non-Publication?:: No  
Suggested Drawing Figure::  
Total Drawing Sheets:: 30  
Small Entity?:: No

**Applicant Information**

Applicant Authority Type:: Inventor  
Primary Citizenship Country:: US  
Status:: Full Capacity  
Given Name:: Robert  
Middle Name:: J.  
Family Name:: Falster  
City of Residence:: London  
Country of Residence:: England  
Street of Mailing Address:: 501 Pearl Drive, P.O. Box 8  
City of Mailing Address:: St. Peters  
State or Province of Mailing  
Address:: MO  
Postal Code of Mailing Address:: 63376  
  
Applicant Authority Type:: Inventor  
Primary Citizenship Country:: Britain  
Status:: Full Capacity



Family Name:: Falster  
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**Correspondence Information**

Correspondence Customer Number:: 000321

**Representative Information**

Representative Customer Number:: 000321

**Domestic Priority Information**

Application::	Continuity Type::	Parent Application::	Parent Filing Date::
This application	Division of	09/416,998	10/13/99
09/416,998	Non- Provisional of	60/104,304	10/14/98

**Assignee Information**

Assignee Name:: MEMC Electronic Materials, Inc.